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DISCRETE POWER DIODES and THYRISTORS
DATA BOOK



ST333S SERIES

INVERTER GRADE THYRISTORS

Stud Version

Features

- All diffused design
- Center amplifying gate
- Guaranteed high dv/dt
- Guaranteed high di/dt
- High surge current capability
- Low thermal impedance
- High speed performance

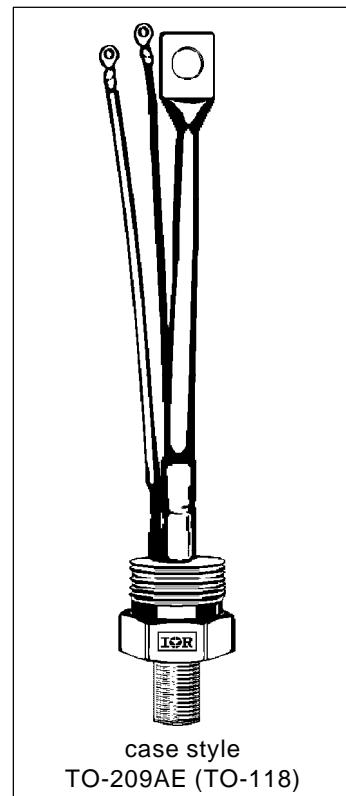
330A

Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

Major Ratings and Characteristics

Parameters	ST333S	Units
$I_{T(AV)}$	330	A
@ T_c	75	°C
$I_{T(RMS)}$	518	A
I_{TSM}	11000	A
@ 50Hz	11000	A
@ 60Hz	11520	A
I^2t	605	KA ² s
@ 50Hz	605	KA ² s
@ 60Hz	550	KA ² s
V_{DRM}/V_{RRM}	400 to 800	V
t_q range	10 to 30	μs
T_j	- 40 to 125	°C



ST333S Series

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , maximum repetitive peak voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_{J\max}$ mA
ST333S	04	400	500	50
	08	800	900	

Current Carrying Capability

Frequency				Units	
50Hz	840	600	1280	A	
400Hz	650	450	1280		
1000Hz	430	230	1090		
2500Hz	140	60	490		
Recovery voltage V_r	50	50	50	V	
Voltage before turn-on V_d	V_{DRM}	V_{DRM}	V_{DRM}		
Rise of on-state current di/dt	50	50	-	A/ μ s	
Case temperature	50	75	50	75	°C
Equivalent values for RC circuit	10Ω / 0.47μF	10Ω / 0.47μF	10Ω / 0.47μF		

On-state Conduction

Parameter	ST333S	Units	Conditions					
$I_{T(AV)}$ Max. average on-state current @ Case temperature	330	A	180° conduction, half sine wave					
	75	°C						
$I_{T(RMS)}$ Max. RMS on-state current	518		DC @ 63°C case temperature					
I_{TSM} Max. peak, one half cycle, non-repetitive surge current	11000	A	$t = 10ms$	No voltage reapplied	Sinusoidal half wave, Initial $T_J = T_{J\max}$			
	11520							
	9250		$t = 10ms$	100% V_{RRM} reapplied				
	9700							
I^2t Maximum I^2t for fusing	605	KA ² s	$t = 10ms$	No voltage reapplied	Initial $T_J = T_{J\max}$			
	550							
	430		$t = 10ms$	100% V_{RRM} reapplied				
	390							
$I^{2\sqrt{t}}$ Maximum $I^{2\sqrt{t}}$ for fusing	6050	KA ² s	$t = 0.1$ to $10ms$, no voltage reapplied					

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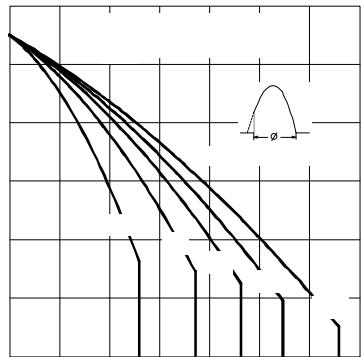


Fig. 1 - Current Ratings Characteristics

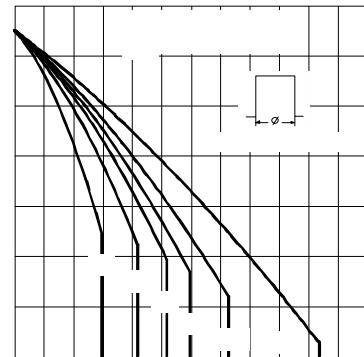


Fig. 2 - Current Ratings Characteristics

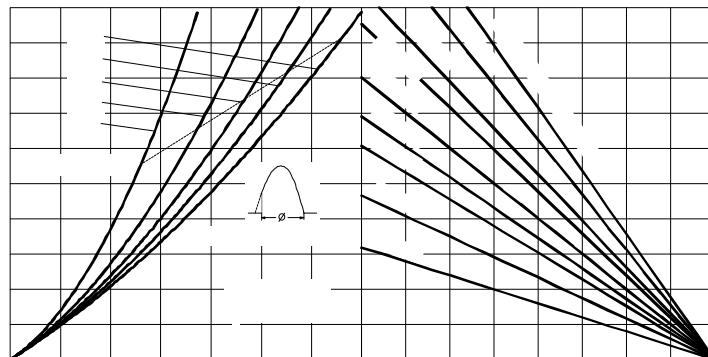


Fig. 3 - On-state Power Loss Characteristics

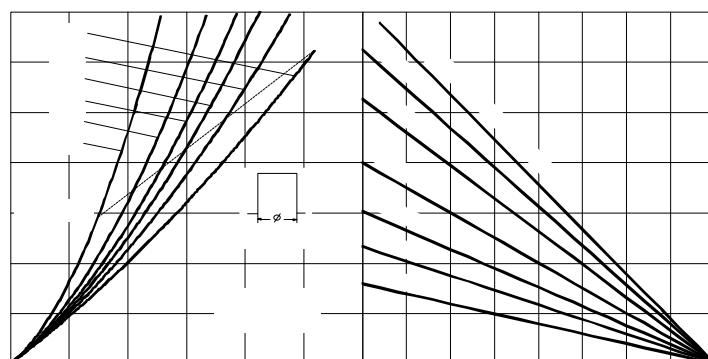


Fig. 4 - On-state Power Loss Characteristics

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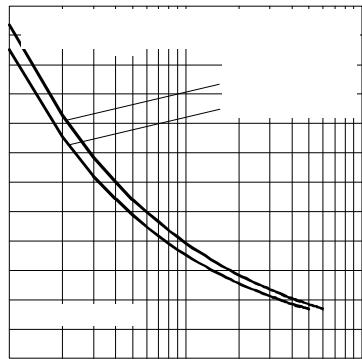


Fig. 5 - Maximum Non-repetitive Surge Current

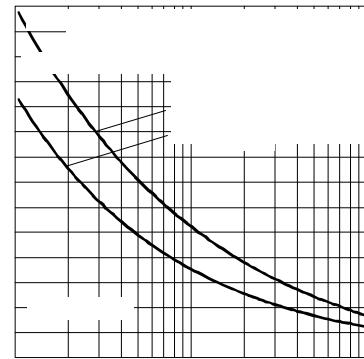


Fig. 6 - Maximum Non-repetitive Surge Current

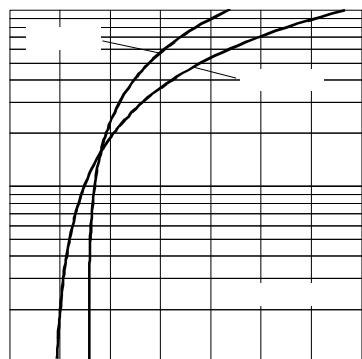


Fig. 7 - On-state Voltage Drop Characteristics

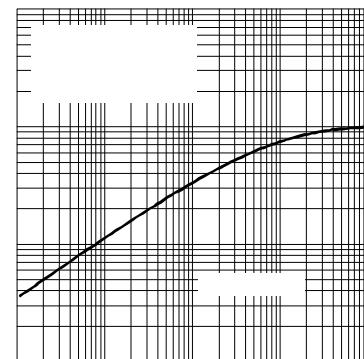


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

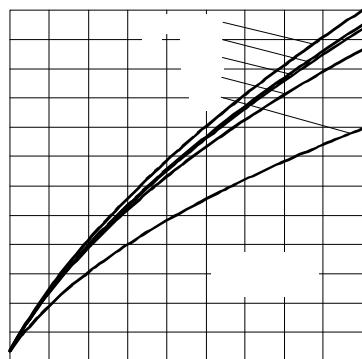


Fig. 9 - Reverse Recovered Charge Characteristics

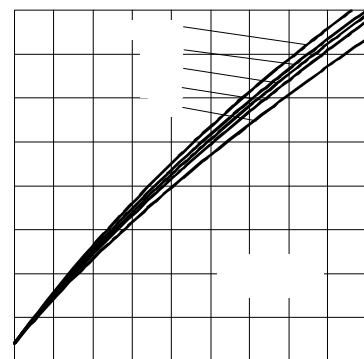


Fig. 10 - Reverse Recovery Current Characteristics

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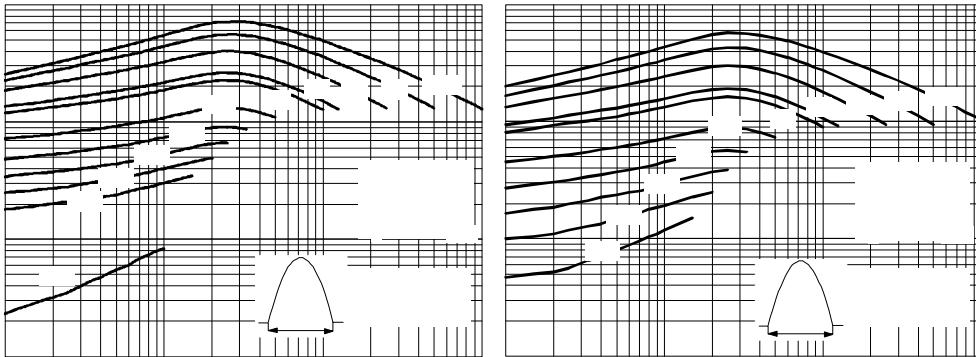


Fig. 11 - Frequency Characteristics

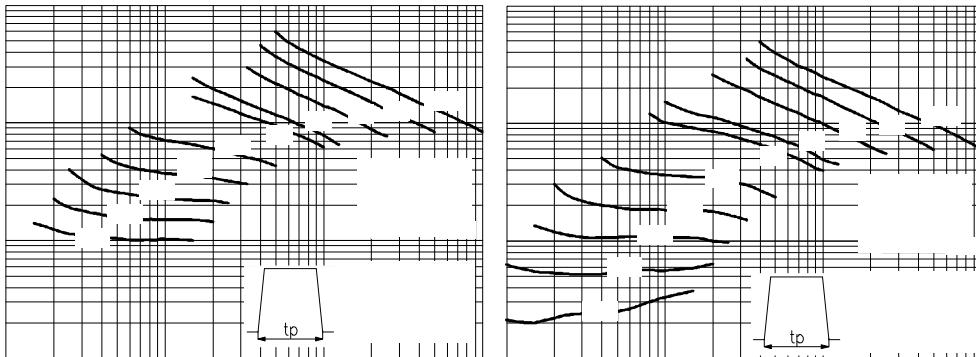


Fig. 12 - Frequency Characteristics

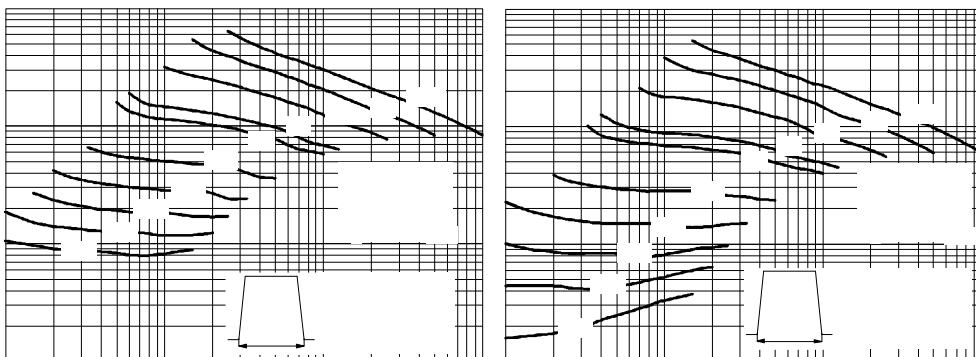


Fig. 13 - Frequency Characteristics

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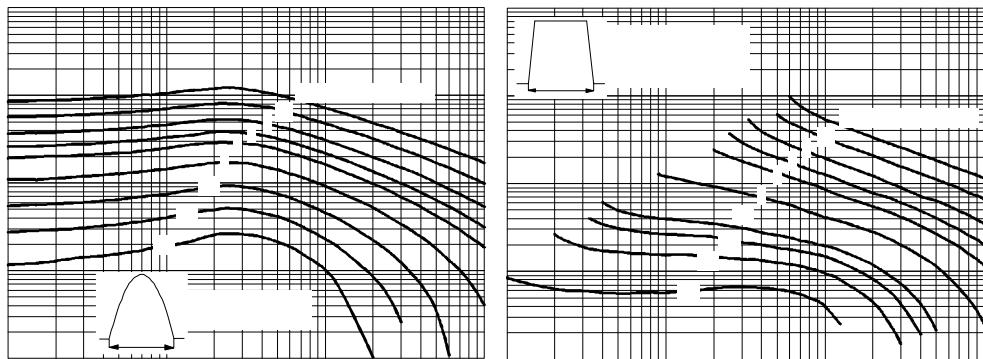


Fig. 14 - Maximum On-state Energy Power Loss Characteristics

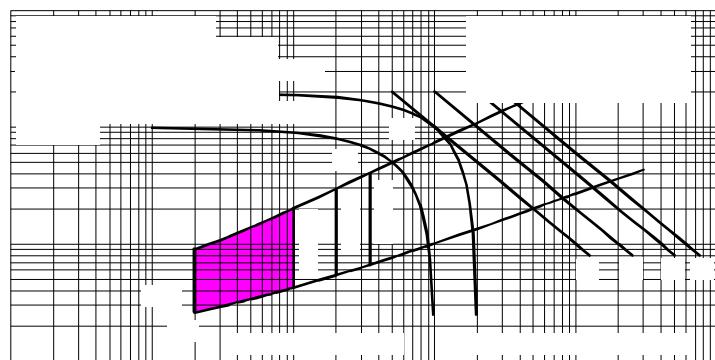


Fig. 15 - Gate Characteristics

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On-state Conduction

Parameter	ST333S	Units	Conditions
V_{TM} Max. peak on-state voltage	1.51	V	$I_{TM} = 1040A, T_J = T_J \text{ max}, t_p = 10\text{ms sine wave pulse}$
$V_{T(TO)1}$ Low level value of threshold voltage	0.91		$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}, T_J = T_J \text{ max.})$
$V_{T(TO)2}$ High level value of threshold voltage	0.92		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
r_{t1} Low level value of forward slope resistance	0.58	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}, T_J = T_J \text{ max.})$
r_{t2} High level value of forward slope resistance	0.58		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
I_H Maximum holding current	600	mA	$T_J = 25^\circ\text{C}, I_T > 30\text{A}$
I_L Typical latching current	1000		$T_J = 25^\circ\text{C}, V_A = 12\text{V}, R_a = 6\Omega, I_G = 1\text{A}$

Switching

Parameter	ST333S	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	$\text{A}/\mu\text{s}$	$T_J = T_J \text{ max}, V_{DRM} = \text{rated } V_{DRM}$ $I_{TM} = 2 \times di/dt$
t_d Typical delay time	1.0	μs	$T_J = 25^\circ\text{C}, V_{DM} = \text{rated } V_{DRM}, I_{TM} = 50\text{A DC}, t_p = 1\mu\text{s}$ Resistive load, Gate pulse: 10V, 5Ω source
t_q Max. turn-off time	Min 10 Max 30		$T_J = T_J \text{ max}, I_{TM} = 550\text{A}, \text{commutating } di/dt = 40\text{A}/\mu\text{s}$ $V_R = 50\text{V}, t_p = 500\mu\text{s}, dv/dt: \text{see table in device code}$

Blocking

Parameter	ST333S	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	$\text{V}/\mu\text{s}$	$T_J = T_J \text{ max. linear to } 80\% V_{DRM}, \text{higher value available on request}$
I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current	50	mA	$T_J = T_J \text{ max, rated } V_{DRM}/V_{RRM} \text{ applied}$

Triggering

Parameter	ST333S	Units	Conditions
P_{GM} Maximum peak gate power	60	W	$T_J = T_J \text{ max, } f = 50\text{Hz, d\% = 50}$
$P_{G(AV)}$ Maximum average gate power	10		
I_{GM} Max. peak positive gate current	10	A	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J \text{ max, } t_p \leq 5\text{ms}$
$-V_{GM}$ Maximum peak negative gate voltage	5		
I_{GT} Max. DC gate current required to trigger	200	mA	$T_J = 25^\circ\text{C, } V_A = 12\text{V, } R_a = 6\Omega$
V_{GT} Max. DC gate voltage required to trigger	3		
I_{GD} Max. DC gate current not to trigger	20	mA	$T_J = T_J \text{ max, rated } V_{DRM} \text{ applied}$
V_{GD} Max. DC gate voltage not to trigger	0.25		

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Thermal and Mechanical Specifications

Parameter	ST333S	Units	Conditions
T _J Max. junction operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJC} Max. thermal resistance, junction to case	0.10	K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.03		Mounting surface, smooth, flat and greased
T Mounting torque, ± 10%	48.5 (425)	Nm (lbf-in)	Non lubricated threads
wt Approximate weight	535	g	
Case style	TO-209AE (TO-118)		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.008	K/W	T _j = T _j max.
120°	0.013	0.014		
90°	0.017	0.018		
60°	0.025	0.026		
30°	0.041	0.042		

Ordering Information Table

Device Code	ST	33	3	S	08	P	F	M	0																																																								
	1	2	3	4	5	6	7	8	9	10																																																							
1 - Thyristor																																																																	
2 - Essential part number																																																																	
3 - 3 = Fast turn off																																																																	
4 - S = Compression bonding Stud																																																																	
5 - Voltage code: Code x 100 = V _{RRM} (See Voltage Ratings table)																																																																	
6 - P = Stud base 3/4" 16UNF-2A																																																																	
M = Stud base metric threads M24 x 1.5																																																																	
7 - Reapplied dv/dt code (for t _q test condition)																																																																	
8 - t _q code																																																																	
9 - 0 = Eyelet terminals (Gate and Aux. Cathode Leads)																																																																	
1 = Fast-on terminals (Gate and Aux. Cathode Leads)																																																																	
3 = Threaded top terminal 3/8" 24UNF-2A																																																																	
10 - Critical dv/dt:																																																																	
None = 500V/μsec (Standard value)																																																																	
L = 1000V/μsec (Special selection)																																																																	
dv/dt - t_q combinations available																																																																	
<table border="1"> <thead> <tr> <th>dv/dt (V/μs)</th> <th>20</th> <th>50</th> <th>100</th> <th>200</th> <th>400</th> </tr> </thead> <tbody> <tr> <td>t_q (μs)</td> <td>10</td> <td>CN</td> <td>DN</td> <td>EN</td> <td>--</td> <td>--</td> </tr> <tr> <td></td> <td>12</td> <td>CM</td> <td>DM</td> <td>EM</td> <td>FM *</td> <td>--</td> </tr> <tr> <td></td> <td>15</td> <td>CL</td> <td>DL</td> <td>EL</td> <td>FL *</td> <td>HL</td> </tr> <tr> <td></td> <td>18</td> <td>CP</td> <td>DP</td> <td>EP</td> <td>FP</td> <td>HP</td> </tr> <tr> <td></td> <td>20</td> <td>CK</td> <td>DK</td> <td>EK</td> <td>FK</td> <td>HK</td> </tr> <tr> <td></td> <td>25</td> <td>--</td> <td>--</td> <td>--</td> <td>FJ</td> <td>HJ</td> </tr> <tr> <td></td> <td>30</td> <td>--</td> <td>--</td> <td>--</td> <td>--</td> <td>HH</td> </tr> </tbody> </table>											dv/dt (V/μs)	20	50	100	200	400	t _q (μs)	10	CN	DN	EN	--	--		12	CM	DM	EM	FM *	--		15	CL	DL	EL	FL *	HL		18	CP	DP	EP	FP	HP		20	CK	DK	EK	FK	HK		25	--	--	--	FJ	HJ		30	--	--	--	--	HH
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*Standard part number. All other types available only on request.																																																																	

ST333S Series

Outline Table

